FILE COPY

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: Shigeo OHSAKA, et al.

Serial Number: 09/456,531

Group Art Unit: 2812

Date: February 9, 2000

Filed: December 8, 1999

Attention: Appln Processing Division, Customer Correction Branch

For:

ELECTRODE STRUCTURE, PROCESS FOR FABRICATING ELECTRODE STRUCTURE AND SEMICONDUCTOR LIGHT-EMITTING DEVICE RECEIVED

REQUEST FOR CORRECTED FILING RECEIPT

WAR S 8 SUUU

TECHNOLOGY CENTER 2800

Assistant Commissioner for Patents Washington, D.C. 20231

Sir:

Please supply the undersigned attorney with a corrected filing receipt for the aboveidentified application. The undersigned also respectfully requests that the Patent and Trademark Office records be amended to reflect the correction.

In reviewing the official Filing Receipt, we noted an error in that there is a typographical error in the title (a comma, --,--should be inserted between "STRUCTURE" and "PROCESS"). A copy of the Declaration is enclosed which indicates the correct title.

We are enclosing a copy of the filing receipt with the corrections highlighted.

In the event that any fees are required in connection with this paper, please charge our Deposit Account No. 01-2340.

Respectfully submitted,

ARMSTRONG, WESTERMAN, HATTORI, McLELAND & NAUGHTON

Mel R. Quintos
Attorney for Applicants
Reg. No. 31,898

Atty. Docket No. 991387 1725 K Street, N.W., Suite 1000 Washington, DC 20006 Tel: (202) 659-2930

Tel: (202) 659-2930 Fax: (202) 887-0357

MRQ/cs

Enclosures: Copies of Filing Receipt & Declaration

PTO-103X (Rev. 6-99)

FILING RECEIPT



UNITED STATES PARTMENT OF COMMERCE Patent and Trademark Office ASSISTANT SECRETARY AND COMMISSIONER OF PATENTS AND TRADEMARKS Washington, D.C. 20231

APPLICATION NUMBER	FILING DATE	GRP ART UNIT	FIL FEE REC'D	ATTORNEY DOCKET NO.	DRWGS	TOT CL	IND CL
09/456,531	12/08/99	2812	\$994.00	991387	14	18	6

ARMSTRONG WESTERMAN HA MCLELAND & NAUGHTON 1725 K STREET N W SUITE WASHINGTON DC 20006 ARMSTRONG, WESTERMAN, HATTOR MCLELAND & NAUGHTON

Receipt is acknowledged of this nonprovisional Patent Application. It will be considered in its order and you will be notified as to the results of the examination. Be sure to provide the U.S. APPLICATION NUMBER, FILING DATE, NAME OF APPLICANT, and TITLE OF INVENTION when inquiring about this application. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filing Receipt, please write to the Office of Initial Patent Examination's Customer Service Center. Please provide a copy of this Filing Receipt with the changes noted thereon. If you received a "Notice to File Missing Parts of Application" ("Missing Parts Notice") in this application, please submit any corrections to this Filing Receipt with your reply to the "Missing Parts Notice." When the PTO processes the reply to the "Missing Parts Notice," the PTO will generate another Filing Receipt incorporating the requested corrections (if appropriate).

Applicant(s)

SHIGEO OHSAKA, YAMANASHI-KEN, JAPAN; SHINICHI DOMOTO, YAMANASHI-KEN, JAPAN; NOBUMASA OKADA, YAMANASHI-KEN, JAPAN.

FOREIGN APPLICATIONS-

JAPAN

11-73500/1999

03/18/99 🐇

IF REQUIRED, FOREIGN FILING LICENSE GRANTED 01/24/00 TITLE

ELECTRODE STRUCTURE PROCESS FOR FABRICATING ELECTRODE STRUCTURE AND SEMICONDUCTOR LIGHT FEMITTING DEVICE

PRELIMINARY CLASS: /438

Please insert ","

TEAM: 01 DATE: 01/24/00 DATA ENTRY BY: BLIZZARD, SHARON .L

(See reverse for new important information)

Declaration and Power of Attorney for U.S. Patent Application

特許出願宣言書及び委任状

Japanese Language Declaration

日本語宣言書



下一の氏名の発明者として、私は以下の通り宜言します。 As a

As a below named inventor, I hereby declare that:

· 私の住所、私杏箱、国籍は下記の私の氏名の後に記載された通りです。

My residence, post office address and citizenship are as stated next to my name.

下記の名称の発明に関して請求範囲に記載され、特許出願している発明内容について、私が最初かつ唯一の発明者(下記の氏名が一つの場合)もしくは最初かつ共同発明者であると(下記の名称が複数の場合)信じています。

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled

ELECTRODE STRUCTURE, PROCESS FOR

FABRICATING ELECTRODE STRUCTURE

AND SEMICONDUCTOR LIGHT-EMITTING DEVICE

上記発明の明細書(下記の欄でx印がついていない場合は、本書に添付)は、

the specification of which is attached hereto unless the following box is checked:

□ ______」 □ 」 □ 月 __ 日 に提出され、米国出願番号または特許協定条約 国際出願番号を ______とし、 (該当する場合) ______ に訂正されました。 was filed on ______as United States Application Number or PCT International Application Number ______and was amended on _____(If applicable).

私は、特許請求範囲を含む上記訂正後の明細書を検討し、 内容を理解していることをここに表明します。

I hereby state that I have reviewed and understand the contents of the above identified specification, including the claims, as amended by any amendment referred to above.

私は、連邦規則法典第37編第1条56項に定義されるとおり、特許資格の有無について重要な情報を開示する義務があることを認めます。

I acknowledge the duty to disclose information which is material to patentability as defined in Title 37, Code of Federal Regulations, Section 1.56.





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Bib Data Sheet



UNITED STATES DEPARTMENT OF COMMERCE Patent and Trademark Office

Address: COMMISSIONER OF PATENTS AND TRADEMARKS Washington, D.C. 20231

SERIAL NUMB 09/456,531	FILING DATE 12/08/1999 RULE _	CLASS 438	GROUP ART 2812	UNIT	ATTORNEY DOCKET NO. 991387					
APPLICANTS SHIGEO OHSAKA, YAMANASHI-KEN, JAPAN; SHINICHI DOMOTO, YAMANASHI-KEN, JAPAN; NOBUMASA OKADA, YAMANASHI-KEN, JAPAN; ** CONTINUING DATA **********************************										
IF REQUIRED, FOREIGN FILING LICENSE GRANTED ** ** 01/24/2000										
Foreign Priority claime 35 USC 119 (a-d) cond met Verified and Acknowledged	ditions yes no Met at	fter STATE OR COUNTRY JAPAN	SHEETS DRAWING 14	TOTAL CLAIMS 18	INDEPENDENT CLAIMS 6					
ADDRESS ARMSTRONG WI MCLELAND & NA 1725 K STREET I WASHINGTON ,[N W SUITE 1000	-								
TITLE ELECTRODE STRUCTURE, PROCESS FOR FABRICATING ELECTRODE STRUCTURE AND SEMICONDUCTOR LIGHT-EMITTING DEVICE										
RECEIVED				All Fees						
	FEES: Authority has been giv No to charge/cre No. for following:	iven in Denes		☐ 1.16 Fees (Filing) ☐ 1.17 Fees (Processing Ext. of						
		edit DEPOSIT ACCOU!	NT time)	time)						
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